



SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 60 to 200 Volts
FORWARD CURRENT - 3.0 Amperes

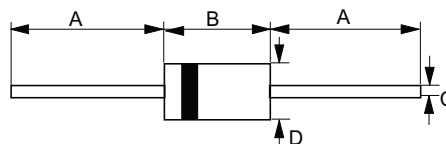
FEATURES

- Metal-Semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

MECHANICAL DATA

- Case : JEDEC DO-201AD molded plastic
- Polarity : Color band denotes cathode
- Weight : 1.071grams
- Mounting position : Any

DO-201AD



DO-201AD		
Dim.	Min.	Max.
A	25.4	-
B	8.50	9.50
C	1.20 \varnothing	1.30 \varnothing
D	5.0 \varnothing	5.60 \varnothing
Dimensions in millimeters		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

PARAMETER	SYMBOL	MBR360	MBR380	MBR3100	MBR3150	MBR3200	UNIT
Maximum repetitive peak reverse voltage	VRRM	60	80	100	150	200	V
Maximum RMS voltage	VRMS	42	56	70	105	140	V
Maximum DC blocking voltage	VDC	60	80	100	150	200	V
Maximum average forward rectified current	IF	3.0					A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	IFSM	80.0					A
Maximum instantaneous @TA=25°C	VF	0.7	0.85	0.87	0.9		V
Maximum DC Reverse Current @TA=25°C at Rated DC Blocking Voltage @TA=100°C	IR	0.2 5.0					mA
Typical Junction Capacitance	CJ	150	110	100	80		pF
Typical Thermal Resistance	R θ JA R θ JC	60 15					°C/W
Operating Temperature Range	TJ	-55 to +150					°C
Storage Temperature Range	TSTG	-55 to +150					°C



FIG. 1-TYPICAL FORWARD CURRENT DERATING CURVE

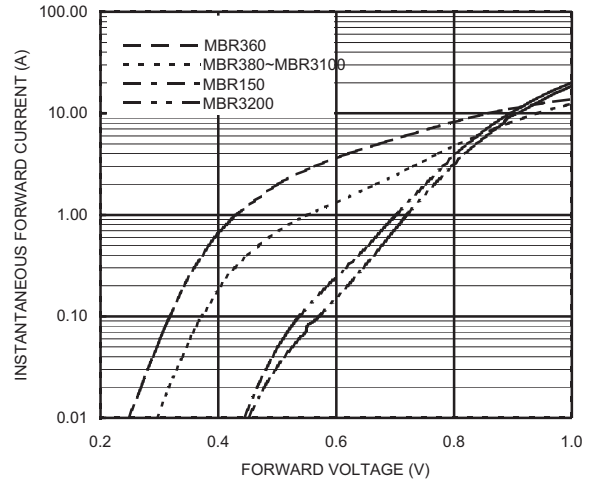
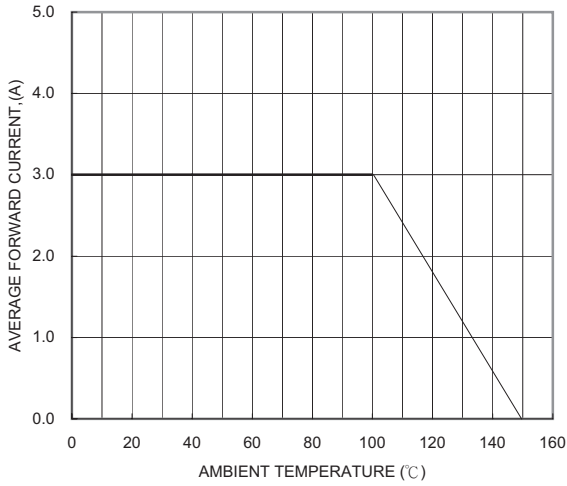


FIG. 3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

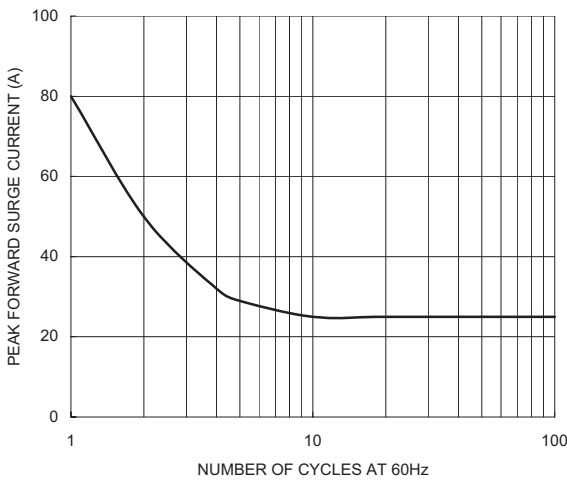


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

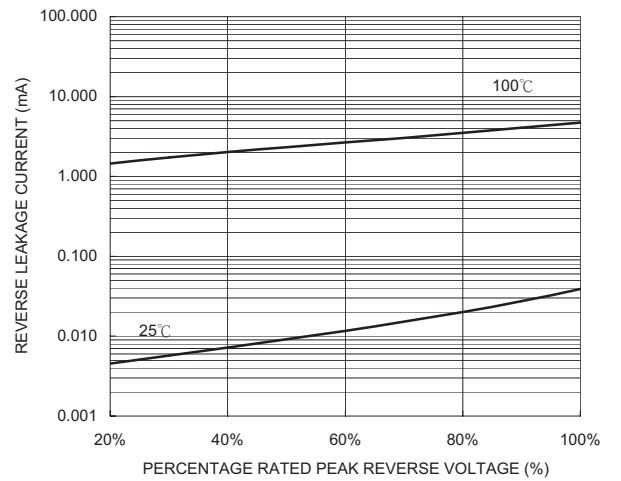


FIG. 5-TYPICAL JUNCTION CAPACITANCE

